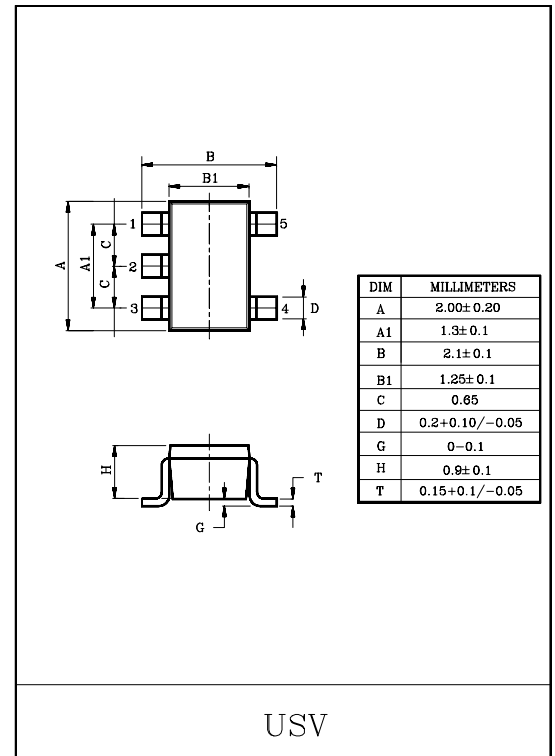


EXCLUSIVE OR GATE

The KIC7S86FU is a high speed C²MOS EXCLUSIVE OR GATE fabricated with silicon gate C²MOS technology. It achieves high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation. Input and output buffers are provided which offer high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

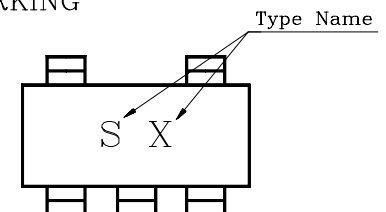
- High Speed : $t_{pd}=10ns(Typ.)$ at $V_{CC}=5V$.
- Low Power Dissipation : $I_{CC}=1\mu A(Max.)$ at $T_a=25^{\circ}C$.
- High Noise Immunity : $V_{NIH}=V_{NIL}=28\% V_{CC}(Min.)$.
- Output Drive Capability : 5 LSTTL Loads.
- Symmetrical Output Impedance : $|I_{OH}|=I_{OL}=2mA(Min.)$
- Balanced Propagation Delays : $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range : $V_{CC(opr)}=2\sim 6V$.



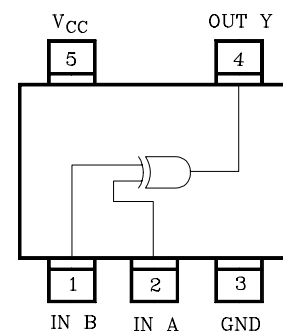
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7	V
DC Input Voltage	V_{IN}	-0.5~ $V_{CC}+0.5$	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC}+0.5$	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±12.5	mA
DC V_{CC} /Ground Current	I_{CC}	±25	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	-65~150	°C
Lead Temperature (10s)	T_L	260	°C

MARKING

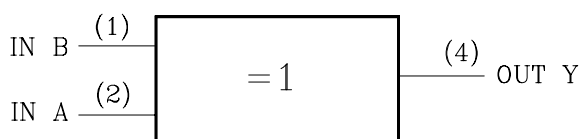


PIN CONNECTION(TOP VIEW)



KIC7S86FU

LOGIC DIAGRAM



TRUTH TABLE

A	B	Y
H	H	L
L	H	H
H	L	H
L	L	L

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 ($V_{CC}=2.0V$) 0~ 500 ($V_{CC}=4.5V$) 0~ 400 ($V_{CC}=6.0V$)	ns

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta=25°C			Ta=-40~85°C		UNIT
				V_{CC}	MIN.	TYP.	MAX.	MIN.	MAX.
High-Level Input Voltage	V_{IH}	-		2.0 4.5 6.0	1.5 3.15 4.2	- - -	- - -	1.5 3.15 4.2	V
Low-Level Input Voltage	V_{IL}	-		2.0 4.5 6.0	- - -	- - -	0.5 1.35 1.8	0.5 1.35 1.8	V
High-Level Output Voltage	V_{OH}	$V_{IN}=V_{IH}$ or V_{IL}	$I_{OH}=-20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	- - -	1.9 4.4 5.9	V
			$I_{OH}=-2mA$	4.5 6.0	4.18 5.68	4.31 5.80	- -	4.13 5.63	
			$I_{OH}=-2.6mA$	6.0	5.68	5.80	-	5.63	
Low-Level Output Voltage	V_{OL}	$V_{IN}=V_{IL}$ or V_{IH}	$I_{OL}=20\mu A$	2.0 4.5 6.0	- - -	0.0 0.0 0.1	0.1 0.1 0.1	- - 0.1	V
			$I_{OL}=2mA$	4.5 6.0	- -	0.17 0.18	0.26 0.26	- -	
			$I_{OL}=2.6mA$	6.0	-	0.18	0.26	-	
Input Leakage Current	I_{IN}	$V_{IN}=V_{CC}$ or GND		6.0	-	-	± 0.1	-	μA
Quiescent Supply Current	I_{CC}	$V_{IN}=V_{CC}$ or GND		6.0	-	-	1.0	-	

KIC7S86FU

AC ELECTRICAL CHARACTERISTICS ($C_L=15\text{pF}$, $V_{CC}=5\text{V}$, $T_a=25^\circ\text{C}$, Input $t_r=t_f=6\text{ns}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	$T_a=25^\circ\text{C}$			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	—	—	4	8	ns
Propagation Delay Time	t_{pLH} t_{pHL}	—	—	10	17	

AC ELECTRICAL CHARACTERISTICS ($C_L=50\text{pF}$, Input $t_r=t_f=6\text{ns}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION		$T_a=25^\circ\text{C}$			$T_a=-40\sim 85^\circ\text{C}$		UNIT
			V_{CC}	MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	—	2.0 4.5 6.0	— — —	50 14 12	125 25 21	— — —	155 31 26	ns
Propagation Delay Time	t_{pLH} t_{pHL}	—	2.0 4.5 6.0	— — —	48 12 9	100 20 17	— — —	125 25 21	
Input Capacitance	C_{IN}	—	—	—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)	—	—	18	—	—	—	

Note 1 : C_{PD} defined as the value of internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

$$I_{CC(\text{opr})}=C_{PD}\cdot V_{CC}\cdot f_{IN}+I_{CC}$$